

# **FJPF3305** High Voltage Switch Mode Application

- High Speed Switching
- Suitable for Electronic Ballast and Switching Regulator



## Absolute Maximum Ratings \* Ta = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	700	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	4	A
I <sub>CP</sub>	Collector Current (Pulse)	8	A
I <sub>B</sub>	Base Current	2	A
P <sub>C</sub>	Collector Dissipation ( $T_a = 25^{\circ}C$ )	30	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-65 ~ 150	°C

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

May 2007

Symbol Parameter		Conditions	Min.	Тур.	Max	Units
BV <sub>CBO</sub>	Collector-Base Breakdwon Voltage	$I_{C} = 500 \mu A, I_{E} = 0$	700			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0	400			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 500μA, I <sub>C</sub> = 0	9			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 700V, I <sub>E</sub> = 0			1	μA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			1	μA
h <sub>FE1</sub> h <sub>FE2</sub>	DC Current Gain *	$V_{CE} = 5V, I_C = 1A$ $V_{CE} = 5V, I_C = 2A$	19 8		35 40	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage				0.5 0.6 1.0	V V V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_{C} = 1A, I_{B} = 0.2A$ $I_{C} = 2A, I_{B} = 0.5A$			1.2 1.6	V V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 1A$	4			MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, f = 1MHz		65		pF
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> = 125V			0.8	μS
t <sub>STG</sub>	Storge Time	$I_{\rm C} = 2A = 5I_{\rm B1} = -5I_{\rm B2}$			4.0	μS
t <sub>F</sub>	Fall Time	$-R_{L} = 62.5\Omega$			0.9	μS

Electrical Characteristics \* T<sub>C</sub> = 25°C unless otherwise noted

\* Pulse Test: PW  $\leq 300 \mu s,$  Duty Cycle  $\leq 2\%$ 

## h<sub>FE</sub> Classification

Classification	H1	H2		
h <sub>FE2</sub>	19 ~ 28	26 ~ 35		

## **Typical Performance Characteristics**

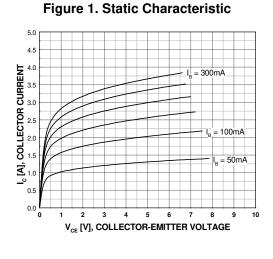


Figure 3. DC Current Gain (O-Grade)

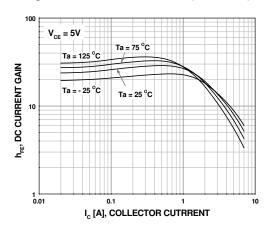


Figure 5. Saturatin Voltage (O-Grade)

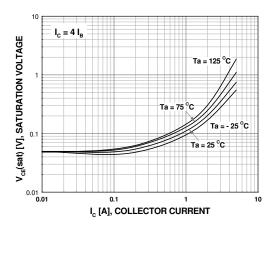


Figure 2. DC Current Gain (R-Grade)

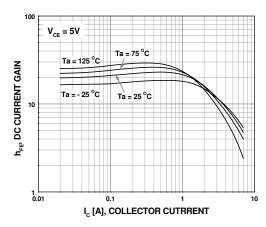


Figure 4. Saturation Voltage (R-Grade)

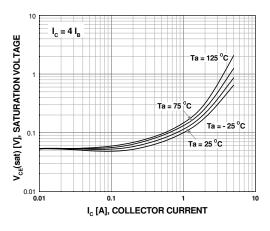
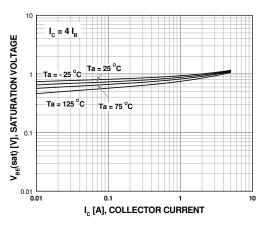


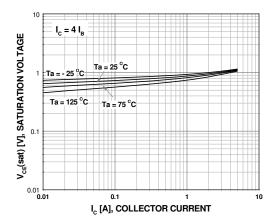
Figure 6. Saturation Voltage (R-Grade)



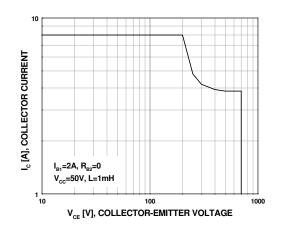
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## Typical Performance Characteristics (Continued)

## Figure 7. Saturation Voltage (O-Grade)









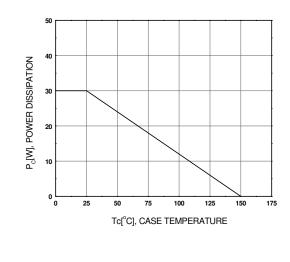


Figure 10. Forward Biased Safe Operating Area

I<sub>c</sub> [A], COLLECTOR CURRENT

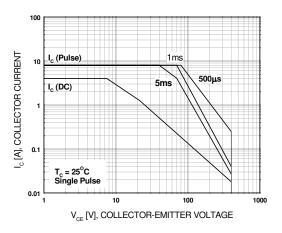


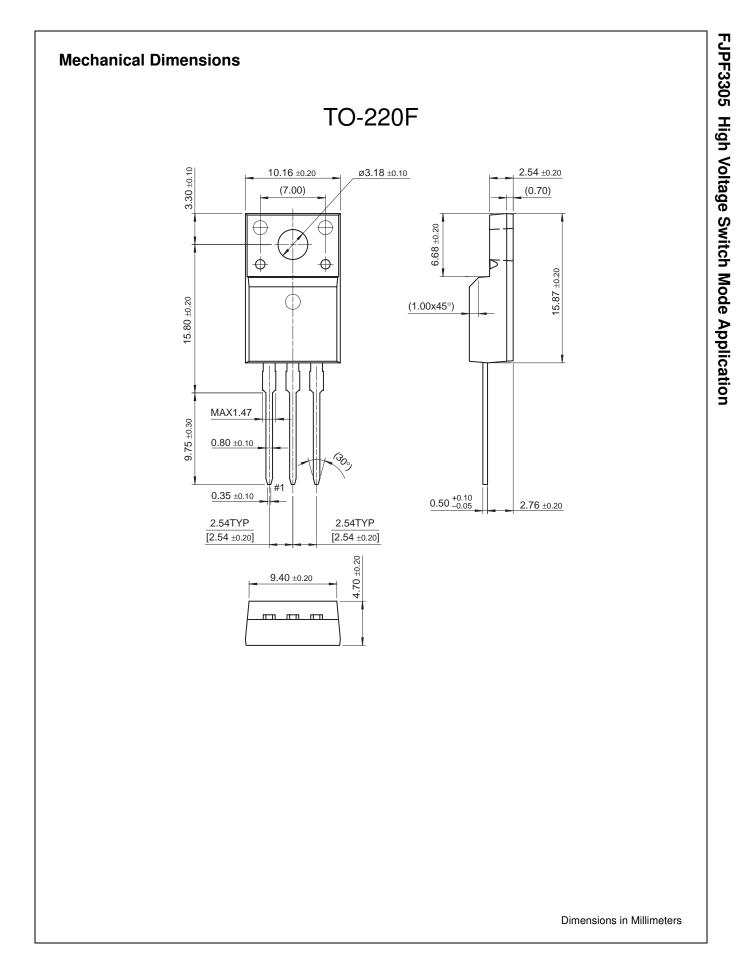
Figure 8. Switching Time

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 $t_{F}$  &  $t_{sr_{G}}$  [ $\mu s$ ], SWITCHING TIME

0.1

0.01 L 0.1  $I_{R_1} = -I_{R_2} = 0.4A$  $V_{CC} = 125V$ 





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Product status/pricing/packaging BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
FJPF3305H1TU	Full Production	Full Production	\$0.412	<u>TO-220F</u>	3	RAIL	N/A
FJPF3305H2TU	Full Production	Full Production	\$0.412	<u>TO-220F</u>	3	RAIL	Line 1: <b>\$Y</b> (Fairchild logo)
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